Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Plastic

Overall Length:

0.210 inches

Overall Height:

0.165 inches

Overall Width:

0.205 inches

End Application:

6625-01-363-6212

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

3.1 limiting voltage

Current Rating Per Characteristic:

20.00 milliamperes source cutoff current preset and 50.00 milliamperes forward current, average outside diameter

Power Rating Per Characteristic:

360.0 milliwatts small-signal input power, common-collector preset

Capacitance Rating In Picofarads:

2.0

Maximum Operating Tempurature Per Measurement Point:

135.0 degrees celsius ambient air

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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